

# WLA0527N

## 0.5 – 2.7 GHz, Low Noise Amplifier

April 2013, REV B



### Key Features

- 0.5 ~ 2.7 GHz, 50 Ohm impedance
- 1.0 dB noise figure
- 15 dB gain
- 1.35:1 VSWR
- 10 dBm P<sub>1dB</sub>
- Precision machined housing
- RoHS compliant

### Applications

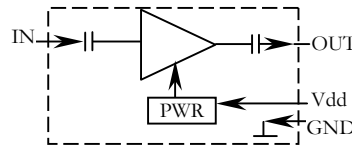
- LTE
- Receiver amplifiers
- RF bench tests
- Mobile base station applications



### Absolute Maximum Ratings

Input CW RF Power	10 dBm
DC Voltage, V <sub>dd</sub>	-0.5, +32V
Operating Temperature	-40°C to +85°C
Storage Temperature	-40°C to +85°C

### Functional Block Diagram



### Ordering Information

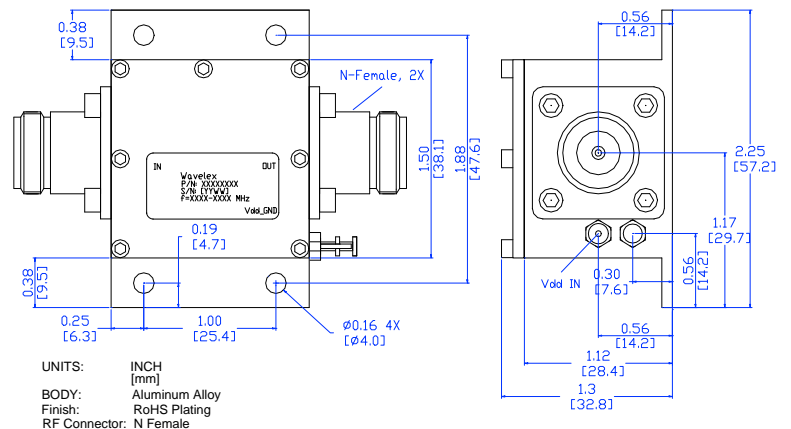
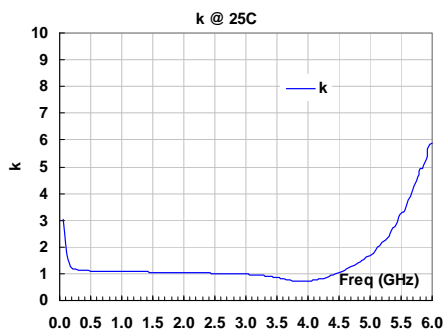
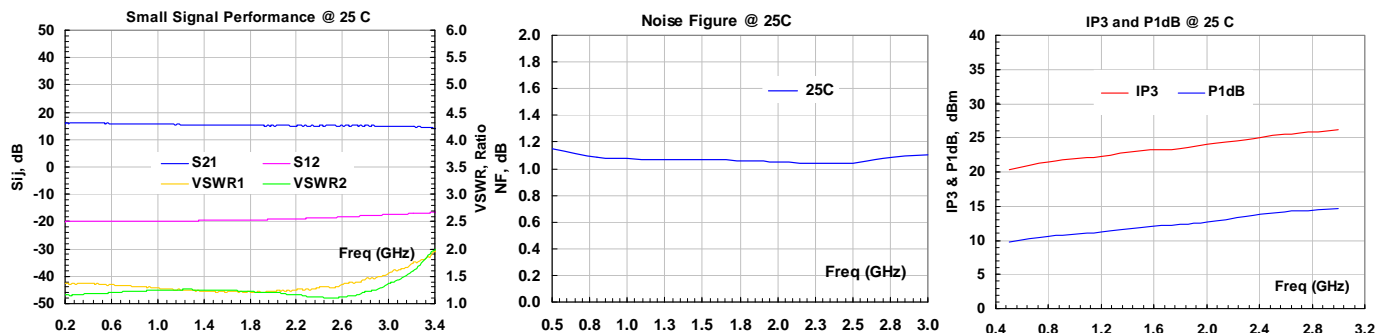
Model	Connectors
WLA0527N	N Female

Marking: WLA0527N

### Specifications (Tested at +25°C)

tem	Symbol	Test Constraints	Min	Nom	Max	Unit
Frequency Range	BW	50 Ohm Impedance	0.5		2.7	GHz
Gain	S <sub>21</sub>	0.5 – 2.7 GHz	13	15	17	dB
Noise Figure	NF	0.5 – 2.7 GHz		1.0	1.4	dB
VSWR	SWR <sub>i</sub>	0.5 – 2.7 GHz, all RF ports		1.35:1	1.5:1	Ratio
Gain Flatness	ΔG	0.5 – 2.7 GHz		+/- 0.5		dB
Reverse Isolation	S <sub>12</sub>	0.5 – 2.7 GHz	15	20		Deg
Output Power 1dB Compression Point	P <sub>1dB</sub>	0.5 – 2.7 GHz	8	10		dBm
Output-Third-Order Interception point	IP <sub>3</sub>	Two-Tone, P <sub>out</sub> = 0 dBm each, 1 MHz separation	18	20		dBm
Current Consumption	I <sub>dd</sub>	V <sub>dd</sub> = +12.0 V		20		mA
Power Supply Operating Voltage	V <sub>dd</sub>		+8	+12	+16	V
Operating Temperature	T <sub>o</sub>		-40		+85	°C
Thermal Resistance	R <sub>th,c</sub>	Junction to case			215	°C/W

### Typical Performance



### Outline, IP-2

Specifications and information are subject to change without notice.